2SC5239

Silicon NPN Triple Diffused Planar Transistor (High Voltage Switchihg Transistor)

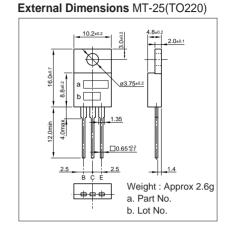
Application: Switching Regulator and General Purpose

■Absolute maximum ratings (Ta=25°C) Symbol Ratings Unit VCBO VCEO 550 ٧ Vebo Ic 3(Pulse6) Α Ιв Рс 50(Tc=25°C) W Τj 150 °C

-55 to +150

Tstg

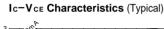
■Electrical Cl	naracteristics	(Ta=25°C)			
Symbol	Conditions	Unit			
Ісво	Vcb=800V	100max	μΑ		
І ЕВО	VEB=7V	100max	μΑ		
V(BR)CEO	Ic=10mA	550min	V		
hfe	Vce=4V, Ic=1A	10 to 30			
Vce(sat)	Ic=1A, IB=0.2A	0.5max	V		
VBE(sat)	Ic=1A, IB=0.2A	1.2max	V		
fт	Vce=12V, Ie=-0.25A	6typ	MHz		
Сов	Vcb=10V, f=1MHz	35typ	рF		

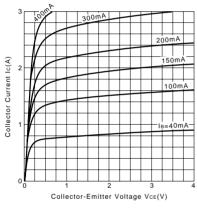


■Typical Switching Characteristics (Common Emitter)

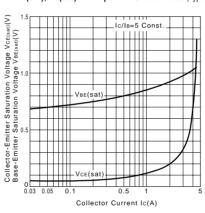
°C

Vcc (V)	RL (Ω)	Ic (A)	VBB1 (V)	VBB2 (V)	I _{B1} (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
250	250	1	10	-5	0.15	-0.45	0.7max	4.0max	0.5max

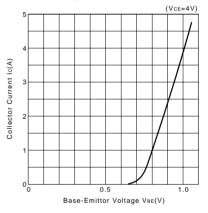




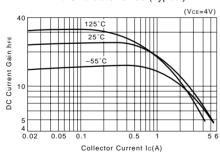
VcE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)



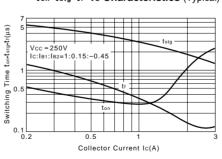
Ic-VBE Temperature Characteristics (Typical)



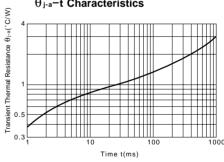
hfe-Ic Characteristics (Typical)



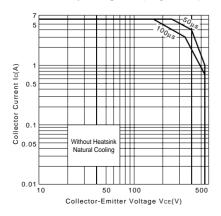
ton•tstg•tf-Ic Characteristics (Typical)



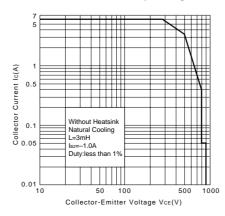
θ_{j-a}-t Characteristics



Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

